

High Power Chip Resistors / Wide Terminal Type 2512, 2010, 1206, 0805

Type: **ERJ A1, B1, B2, B3**



■ Features

- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- RoHS compliant

■ Recommended Applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems
- Current sensing for power supply circuits in a variety of equipment

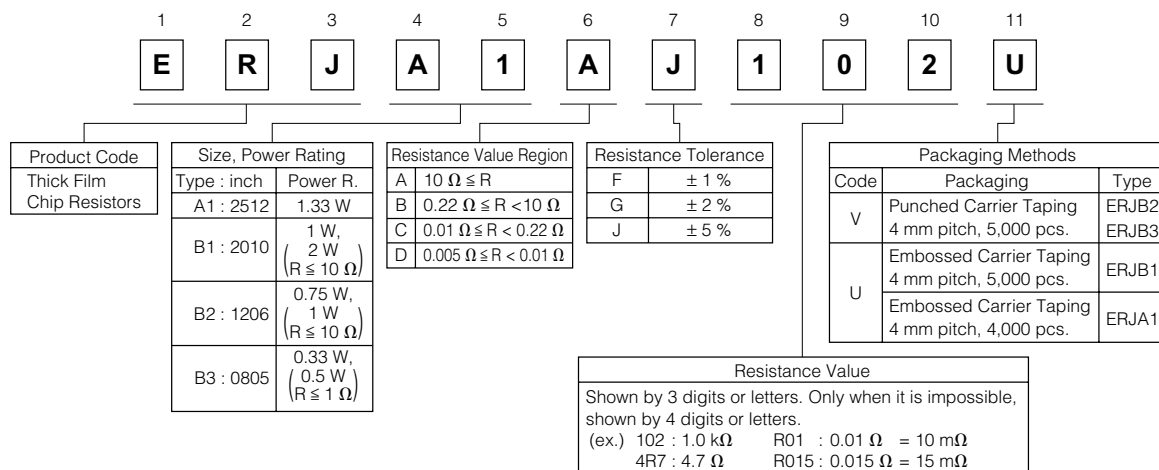
■ Packaging Methods Please see Pages 40 to 43

■ Recommended Land Pattern Please see Pages 44 to 45

■ Recommended Soldering Conditions Please see Page 46

■ Safety Precautions Please see Page 47

■ Explanation of Part Numbers



■ Construction (Example : ERJA1 type)



■ Dimensions in mm (not to scale)

ERJA1 type



Mass (Weight) [1000 pcs.] : 40 g

Dimensions (mm)	L	W	T	A ₁	B ₁
	6.40±0.20	3.20±0.20	0.55±0.10	0.70±0.20	0.45±0.20
Dimensions (mm)	A ₂	B ₂	P	φD	C
	0.70±0.20	1.25±0.15	1.27±0.10	0.30 ^{+0.10} _{-0.20}	0.4 min.

ERJB1 type



Mass (Weight) [1000 pcs.] : 27 g

Dimensions (mm)	L	W	T	a	b
	5.00±0.20	2.50±0.20	0.55±0.20	0.25±0.20	0.90±0.20

ERJB2 type

(R < 10 mΩ)



(10 mΩ ≤ R ≤ 1 MΩ)



Mass (Weight) [1000 pcs.] : 11 g

Dimensions (mm)	L	W	T	a	b
5 mΩ ≤ R < 10 mΩ				0.30±0.20	0.30±0.20
10 mΩ ≤ R < 220 mΩ	3.20±0.20	1.60±0.15	0.65±0.15	0.30±0.20	0.50±0.20
220 mΩ ≤ R ≤ 1 MΩ				0.20±0.20	0.50±0.20

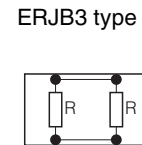
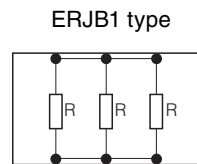
ERJB3 type



Mass (Weight) [1000 pcs.] : 4.8 g

Dimensions (mm)	L	W	T	a	b
	2.00±0.10	1.25±0.10	0.50±0.10	0.25±0.15	0.40±0.15

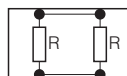
■ Circuit Configuration



< Less than 10 mΩ >



< Low resistance zone >



< High resistance zone >



■ Ratings

Type (inch size)	Power Rating at 70 °C (W)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)
ERJA1 (2512)	1.33	200	400	±1	100 m to 10 k (E24)	R < 100 mΩ : ±350 100 mΩ ≤ R : ±100 (±1%) ±200 (±2%, ±5%)	-55 to +155
				±2, ±5	10 m to 10 k (E24)		
ERJB1 (2010)	1 2(R ≤ 10 Ω) ⁽³⁾	200	400	±1, ±2, ±5	10 m to 10 k (E24)	R < 22 mΩ : ±350 22 mΩ ≤ R < 47 mΩ : ±200 47 mΩ ≤ R < 100 mΩ : ±150 (±1%) ±200 (±2%, ±5%) 100 mΩ ≤ R : ±100 (±1%) ±200 (±2%, ±5%)	-55 to +155
ERJB2 (1206)	0.75 1(R ≤ 10 Ω) ⁽³⁾	200	400	±1, ±2	10 m to 1 M (E24)	R < 22 mΩ : 0 to +300 22 mΩ ≤ R < 47 mΩ : 0 to +200 47 mΩ ≤ R < 100 mΩ : 0 to +150 100 mΩ ≤ R < 220 mΩ : 0 to +150 (±1%) 0 to +200 (±2%, ±5%) 220 mΩ ≤ R : ±100 (±1%) ±200 (±2%, ±5%)	-55 to +155
				±5	5 m to 1 M (5 m to 9 m : 1mΩ step) 10 m to 1 M : E24		
ERJB3 (0805)	0.33 0.5(R ≤ 1 Ω) ⁽³⁾	150	200	±1, ±2, ±5	20 m to 10 (E24)	R < 47 mΩ : 0 to +300 47 mΩ ≤ R ≤ 1 Ω : 0 to +200 1 Ω < R : ±100 (±1%) ±200 (±2%, ±5%)	-55 to +155

(1) Rated Continuous Working Voltage (RCWV) shall be determined from $RCWV = \sqrt{\text{Power Rating} \times \text{Resistance Values}}$, or Limiting Element Voltage listed above, whichever less.

(2) Overload (Short-time Overload) Test Voltage (SOTV) shall be determined from $SOTV = 2.5 \times \text{Power Rating}$ or max. Overload Voltage listed above whichever less.

(3) Please contact us when resistors with guaranteed high power are needed.

Power Derating Curve

For resistors operated in ambient temperature above 70 °C, power rating shall be derated in accordance with the figure on the right.

